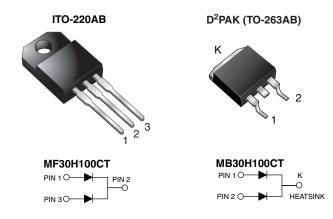
# **MB30H100CT, MF30H100CT**

Vishay General Semiconductor

HALOGEN FREE

# **Dual Common Cathode High Voltage Schottky Rectifier**

High Barrier Technology for Improved High Temperature Performance



| PRIMARY CHARACTERISTICS |  |  |  |  |  |
|-------------------------|--|--|--|--|--|
| I <sub>F(AV)</sub>      | 2 x 15 A                                 |  |  |  |  |
| $V_{RRM}$               | 100 V                                    |  |  |  |  |
| I <sub>FSM</sub> 275 A  |  |  |  |  |  |
| V <sub>F</sub>          | 0.67 V                                   |  |  |  |  |
| I <sub>R</sub>          | 5.0 μA                                   |  |  |  |  |
| T <sub>J</sub> max.     | 175 °C                                   |  |  |  |  |
| Package                 | ITO-220AB, D <sup>2</sup> PAK (TO-263AB) |  |  |  |  |
| Circuit configuration   | Common cathode                           |  |  |  |  |

#### **FEATURES**

- Power pack
- · Guardring for overvoltage protection
- · Low power loss, high efficiency
- Low forward voltage drop
- · Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for D<sup>2</sup>PAK (TO-263AB) package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for ITO-220AB package)
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

### **MECHANICAL DATA**

Case: ITO-220AB, D2PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating

Base P/NHE3\_X - RoHS-compliant, AEC-Q101 qualified ("\_X" denotes revision code e.g. A, B,....)

Base P/NHM3 - RoHS-compliant, halogen-free, AEC-Q101 qualified

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

HE3 and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

| <b>MAXIMUM RATINGS</b> (T <sub>C</sub> = 25 °C unless otherwise note PARAMETER               |              | SYMBOL                            | MB30H100CT   | MF30H100CT   | UNIT |
|--|--------------|-----------------------------------|--------------|--------------|------|
| Device marking code  |              |                                   | MBRB30H100CT | MBRF30H100CT |      |
| Maximum repetitive peak reverse voltage  |              | $V_{RRM}$                         | 100          |              |      |
| Working peak reverse voltage   |              | V <sub>RWM</sub>                  | 100          |              | V    |
| Maximum DC blocking voltage  |              | $V_{DC}$                          | 100          |              | i    |
| Maximum average forward rectified current (fig.1)  | total device | 1                                 | 30<br>15     |              |      |
|  | per diode    | I <sub>F(AV)</sub>                |              |              |      |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode |              | I <sub>FSM</sub>                  | 275          |              | Α    |
| Peak repetitive reverse surge current per diode at t <sub>p</sub> = 2.0 μs, 1 kHz            |              | I <sub>RRM</sub>                  | 1.0          |              |      |
| Voltage rate of change (rated V <sub>R</sub> )   |              | dV/dt                             | 10 000       |              | V/µs |
| Operating junction and storage temperature range   |              | T <sub>J</sub> , T <sub>STG</sub> | -65 to +175  |              | °C   |
| Isolation voltage (ITO-220AB only) from terminal to heat sink t = 1 min                      |              | V <sub>AC</sub>                   | 1500         |              | V    |



# MB30H100CT, MF30H100CT

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| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted) |                               |                       |                         |       |      |  |
|---|-------------------------------|-----------------------|-------------------------|-------|------|--|
| PARAMETER   | SYMBOL                        | TEST CONDITIONS       |                         | VALUE | UNIT |  |
| Maximum instantaneous forward voltage per diode                                   | V <sub>F</sub> (1)            | I <sub>F</sub> = 15 A | T <sub>J</sub> = 25 °C  | 0.82  | V    |  |
|   |                               | I <sub>F</sub> = 15 A | T <sub>J</sub> = 125 °C | 0.67  |      |  |
|   |                               | I <sub>F</sub> = 30 A | T <sub>J</sub> = 25 °C  | 0.93  |      |  |
|   |                               | I <sub>F</sub> = 30 A | T <sub>J</sub> = 125 °C | 0.80  |      |  |
| Maximum reverse current per diode   | I <sub>R</sub> <sup>(2)</sup> | Rated V <sub>R</sub>  | T <sub>J</sub> = 25 °C  | 5.0   | μΑ   |  |
|   |                               |                       | T <sub>J</sub> = 125 °C | 6.0   | mA   |  |

#### Note

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width, ≤ 40 ms

| THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted) |                 |            |            |      |  |
|---|-----------------|------------|------------|------|--|
| PARAMETER   | SYMBOL          | MB30H100CT | MF30H100CT | UNIT |  |
| Typical thermal resistance per diode                                    | $R_{\theta JC}$ | 1.9        | 4.6        | °C/W |  |

| ORDERING INFORMATION          |                   |                 |              |               |               |  |  |
|-------------------------------|-------------------|-----------------|--------------|---------------|---------------|--|--|
| PACKAGE                       | PREFERRED P/N     | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |  |  |
| ITO-220AB                     | MF30H100CTHE3_B/P | 1.99            | Р            | 50/tube       | Tube          |  |  |
| D <sup>2</sup> PAK (TO-263AB) | MB30H100CTHM3/I   | 1.35            | I            | 800/reel      | Tape and reel |  |  |

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### **RATINGS AND CHARACTERISTICS CURVES** ( $T_C = 25$ °C unless otherwise noted)

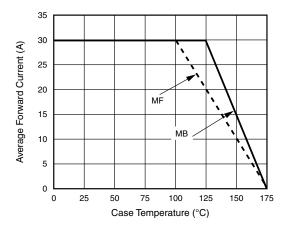


Fig. 1 - Forward Derating Curve Per Diode

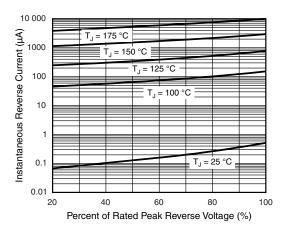


Fig. 4 - Typical Reverse Characteristics Per Diode

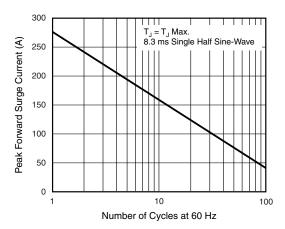


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

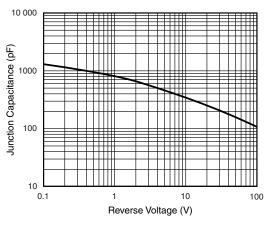


Fig. 5 - Typical Junction Capacitance Per Diode

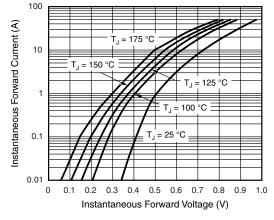


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

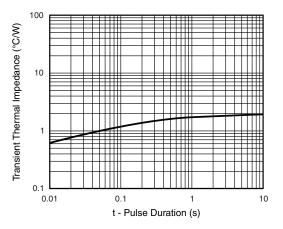
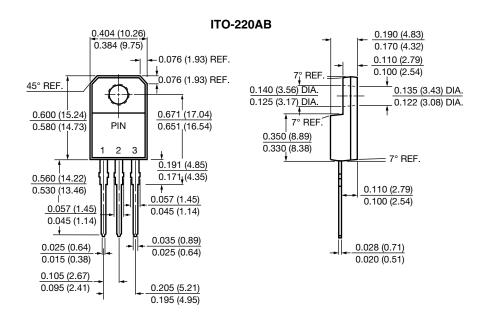


Fig. 6 - Typical Transient Thermal Impedance Per Diode

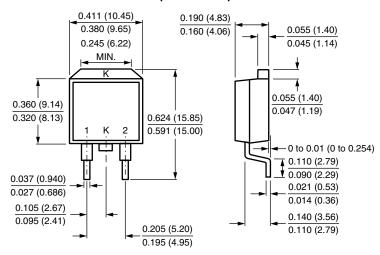


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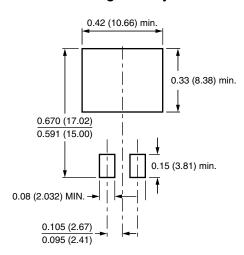
### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



#### D<sup>2</sup>PAK (TO-263AB)



### **Mounting Pad Layout**





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